



# SCH1334 — P-Channel Silicon MOSFET

## General-Purpose Switching Device Applications

### Features

- Low ON-resistance
- High-speed switching
- 1.8V drive
- Halogen free compliance
- Protection diode in

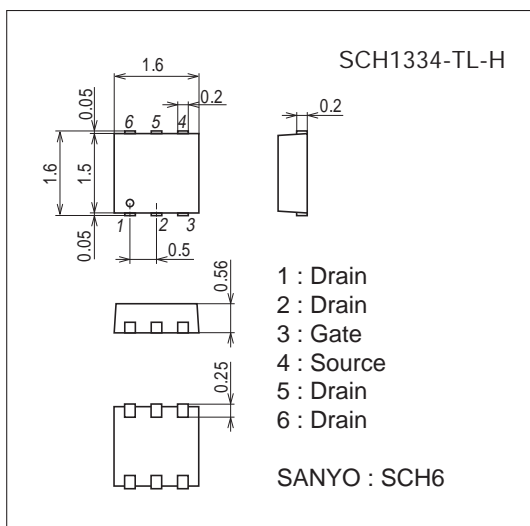
### Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		-12	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±10	V
Drain Current (DC)	I <sub>D</sub>		-1.6	A
Drain Current (Pulse)	I <sub>DP</sub>	PW≤10μs, duty cycles≤1%	-6.4	A
Allowable Power Dissipation	P <sub>D</sub>	When mounted on ceramic substrate (900mm <sup>2</sup> ×0.8mm)	0.8	W
Channel Temperature	T <sub>ch</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

### Package Dimensions

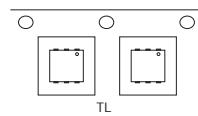
unit : mm (typ)  
7028-002



### Product & Package Information

- Package : SCH6
- JEITA, JEDEC : SOT-563
- Minimum Packing Quantity : 5,000 pcs./reel

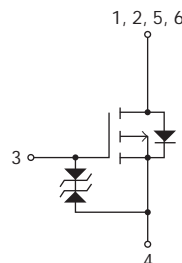
### Packing Type : TL



### Marking



### Electrical Connection

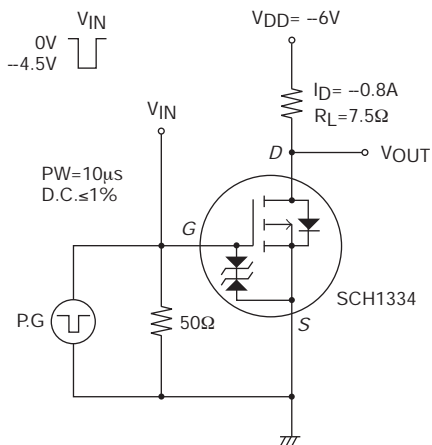


# SCH1334

## Electrical Characteristics at Ta=25°C

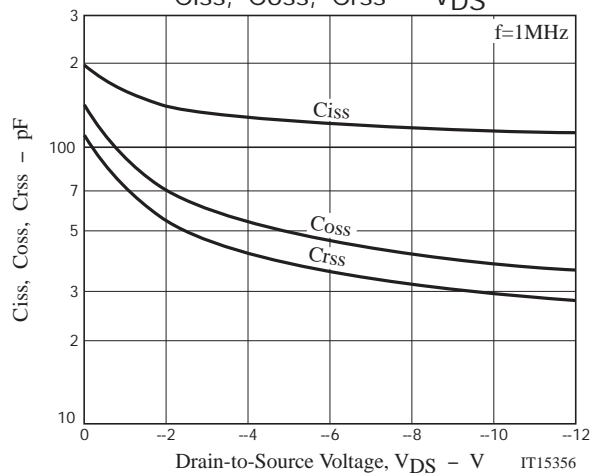
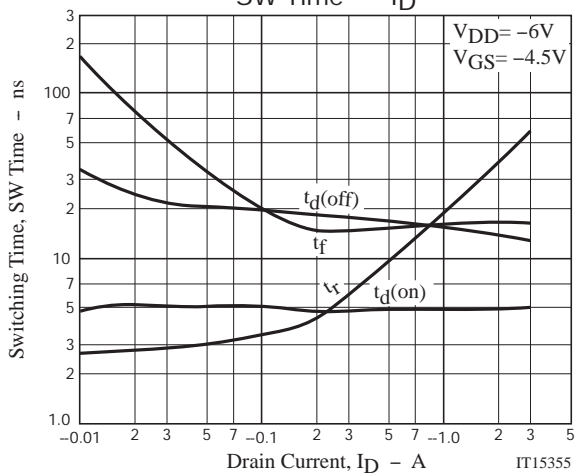
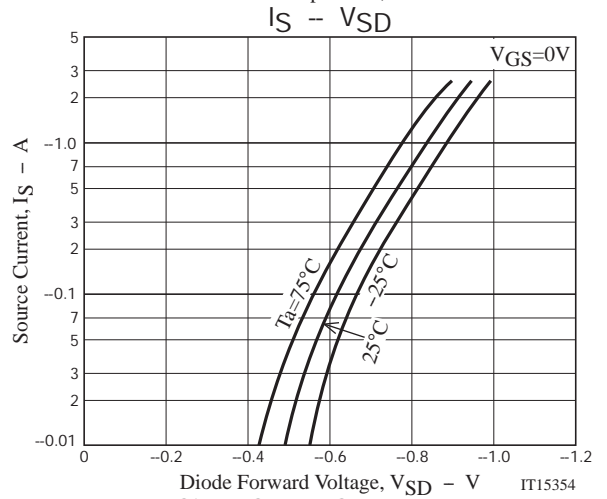
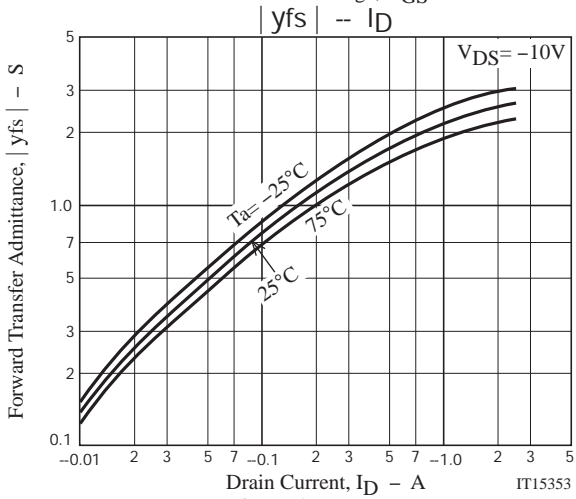
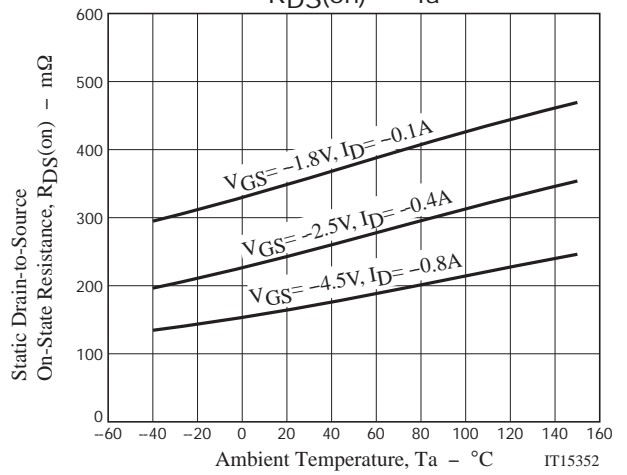
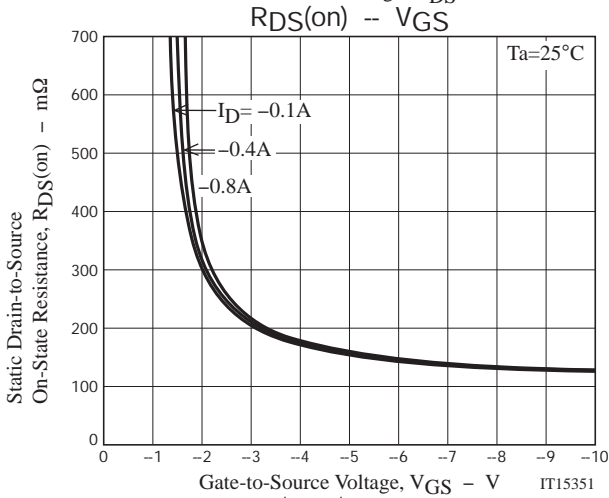
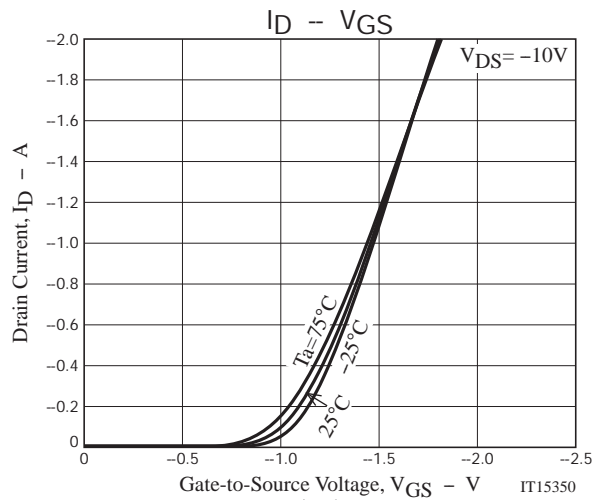
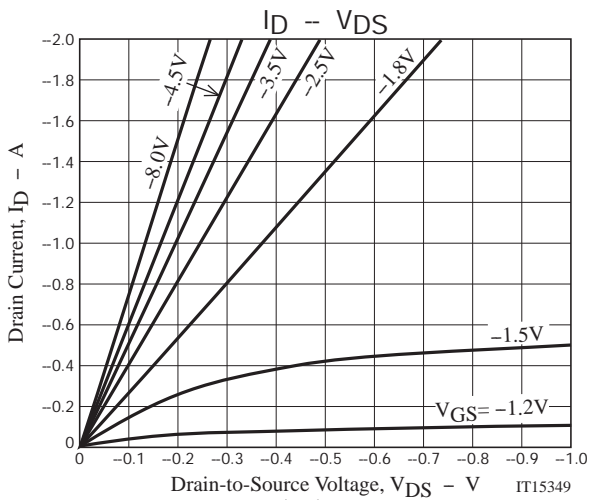
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =-1mA, V <sub>GS</sub> =0V	-12			V
Zero-Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-12V, V <sub>GS</sub> =0V			-10	μA
Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V			±10	μA
Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> =-6V, I <sub>D</sub> =-1mA	-0.4		-1.3	V
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> =-6V, I <sub>D</sub> =-0.8A	1.2	2.1		S
Static Drain-to-Source On-State Resistance	R <sub>DS(on)1</sub>	I <sub>D</sub> =-0.8A, V <sub>GS</sub> =-4.5V		165	215	mΩ
	R <sub>DS(on)2</sub>	I <sub>D</sub> =-0.4A, V <sub>GS</sub> =-2.5V		245	345	mΩ
	R <sub>DS(on)3</sub>	I <sub>D</sub> =-0.1A, V <sub>GS</sub> =-1.8V		370	560	mΩ
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-6V, f=1MHz		120		pF
Output Capacitance	C <sub>oss</sub>			46		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			36		pF
Turn-ON Delay Time	t <sub>d(on)</sub>		See specified Test Circuit.		4.9	
Rise Time	t <sub>r</sub>			17.5		ns
Turn-OFF Delay Time	t <sub>d(off)</sub>			16.0		ns
Fall Time	t <sub>f</sub>			16.5		ns
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =-6V, V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-1.6A			1.6	
Gate-to-Source Charge	Q <sub>gs</sub>			0.27		nC
Gate-to-Drain "Miller" Charge	Q <sub>gd</sub>			0.43		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1.6A, V <sub>GS</sub> =0V		-0.88	-1.2	V

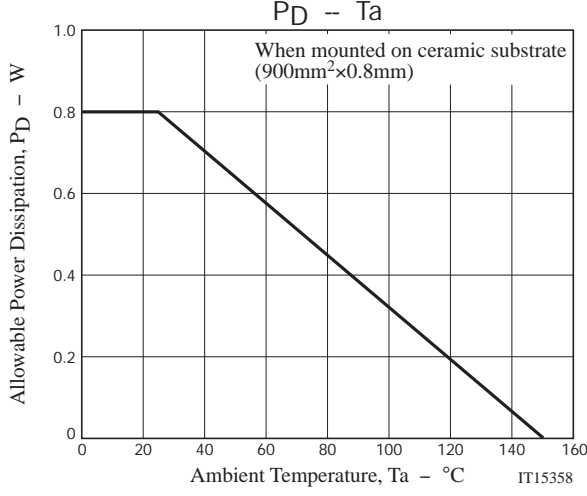
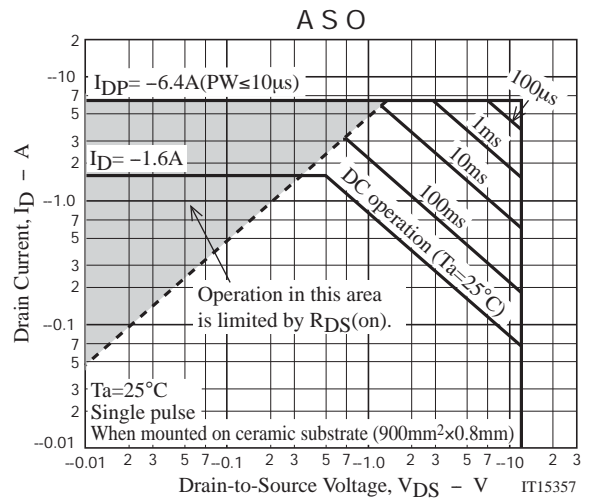
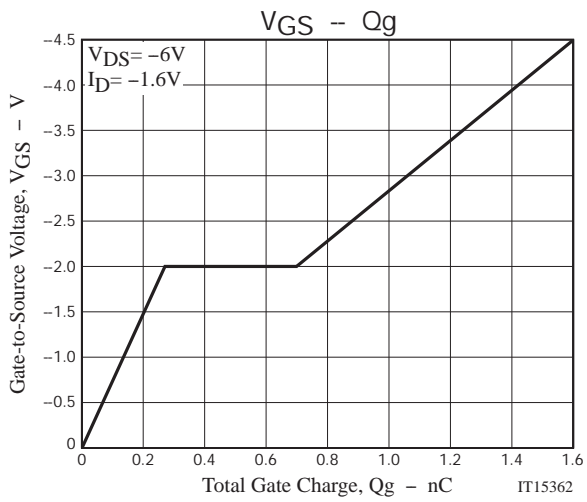
## Switching Time Test Circuit



## Ordering Information

Device	Package	Shipping	memo
SCH1334-TL-H	SCH6	5,000pcs./reel	Pb Free and Halogen Free





Taping Specification

SCH1334-TL-H

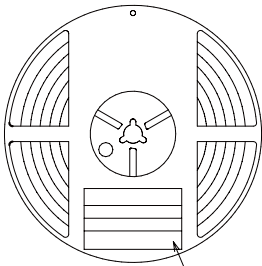
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
SCH6	SCH6	5,000	25,000	150,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label  
(unit:mm)

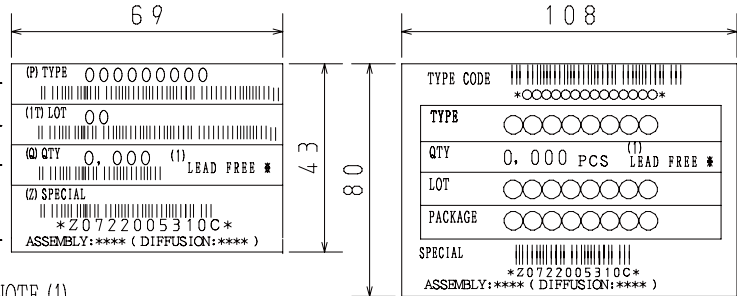
Outer box label  
It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.

Packing method



Type No.  
LOT No.  
Quantity  
Origin

Reel label



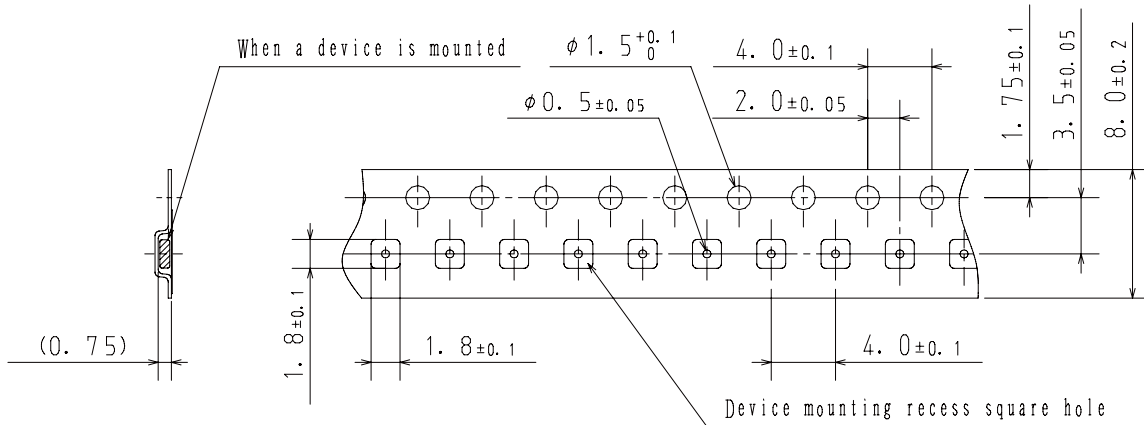
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

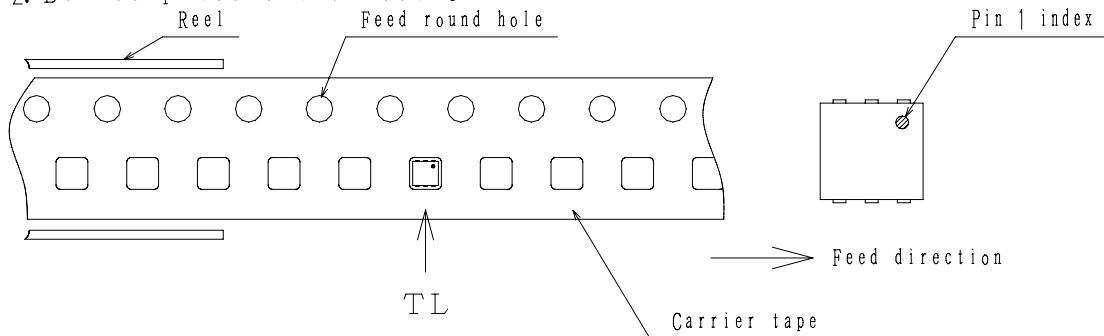
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



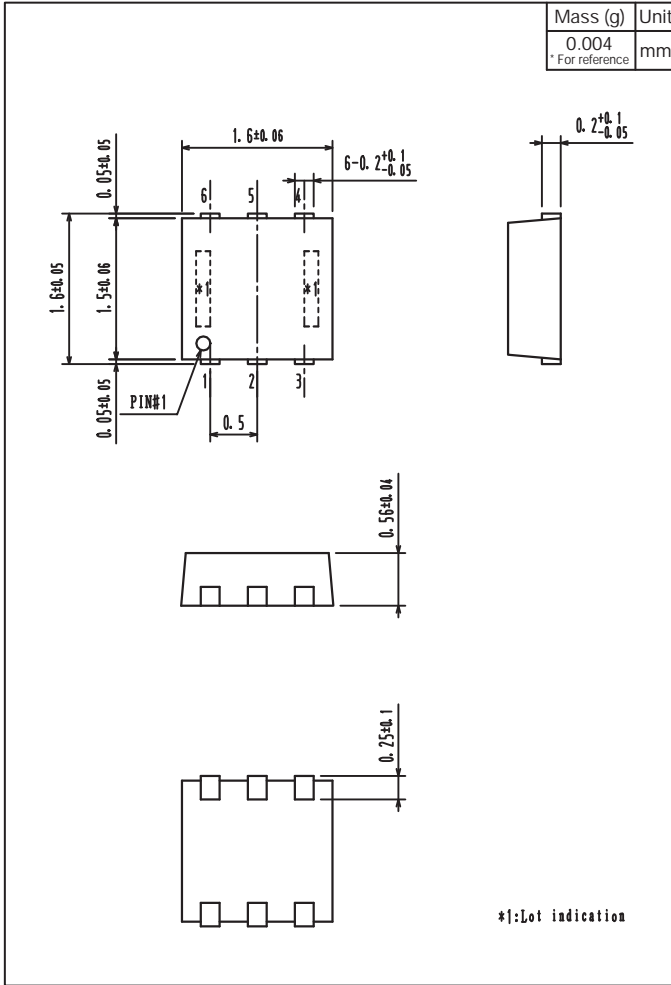
2-2. Device placement direction



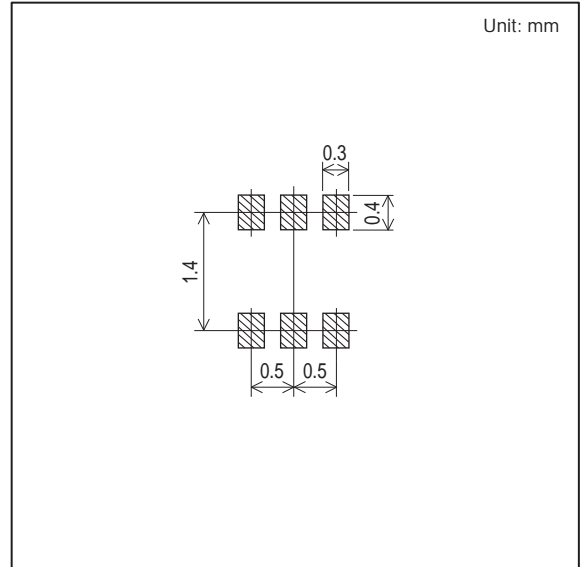
Those with pin 1 index on the feed hole side.....TL

# SCH1334

## Outline Drawing SCH1334-TL-H



## Land Pattern Example



Note on usage : Since the SCH1334 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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